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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

Details

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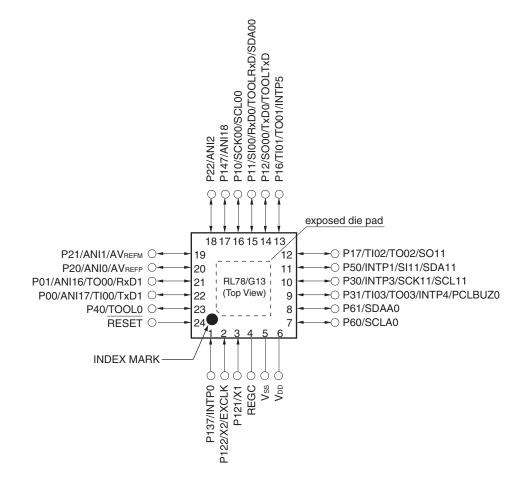
Details	
Product Status	Obsolete
Core Processor	RL78
Core Size	16-Bit
Speed	32MHz
Connectivity	CSI, I ² C, LINbus, UART/USART
Peripherals	DMA, LVD, POR, PWM, WDT
Number of I/O	64
Program Memory Size	128KB (128K x 8)
Program Memory Type	FLASH
EEPROM Size	8K x 8
RAM Size	12K x 8
Voltage - Supply (Vcc/Vdd)	1.6V ~ 5.5V
Data Converters	A/D 17x8/10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	80-LQFP
Supplier Device Package	80-LFQFP (12x12)
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f100mgafb-v0

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

1.3.2 24-pin products

• 24-pin plastic HWQFN (4 × 4 mm, 0.5 mm pitch)

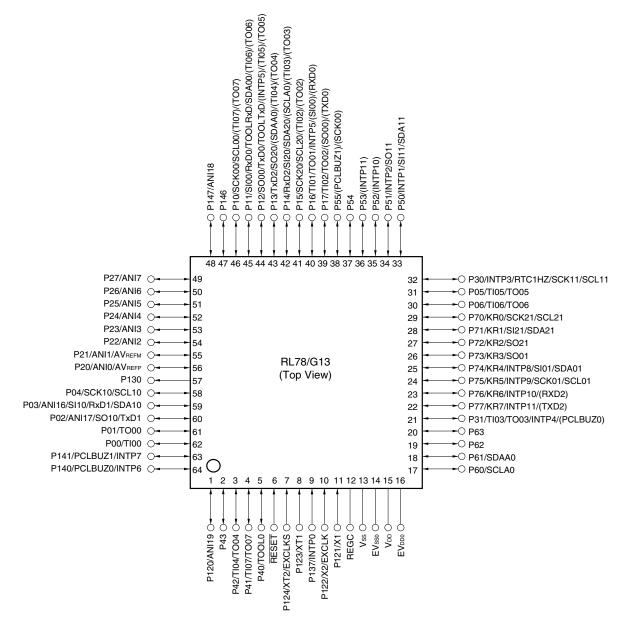


- Caution Connect the REGC pin to Vss via a capacitor (0.47 to 1 μ F).
- Remarks 1. For pin identification, see 1.4 Pin Identification.
 - 2. It is recommended to connect an exposed die pad to Vss.



1.3.11 64-pin products

- 64-pin plastic LQFP (12 × 12 mm, 0.65 mm pitch)
- 64-pin plastic LFQFP (10 × 10 mm, 0.5 mm pitch)



Cautions 1. Make EVsso pin the same potential as Vss pin.

- 2. Make VDD pin the potential that is higher than EVDD0 pin.
- 3. Connect the REGC pin to Vss via a capacitor (0.47 to 1 μ F).
- Remarks 1. For pin identification, see 1.4 Pin Identification.
 - 2. When using the microcontroller for an application where the noise generated inside the microcontroller must be reduced, it is recommended to supply separate powers to the V_{DD} and EV_{DD0} pins and connect the V_{SS} and EV_{SS0} pins to separate ground lines.
 - **3.** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR). Refer to Figure 4-8 Format of Peripheral I/O Redirection Register (PIOR) in the RL78/G13 User's Manual.



1.4 Pin Identification

ANI0 to ANI14,		REGC:	Regulator capacitance
ANI16 to ANI26:	Analog input	RESET:	Reset
AVREFM:	A/D converter reference	RTC1HZ:	Real-time clock correction clock
	potential (– side) input		(1 Hz) output
AVREFP:	A/D converter reference	RxD0 to RxD3:	Receive data
	potential (+ side) input	SCK00, SCK01, SCK10,	
EVDD0, EVDD1:	Power supply for port	SCK11, SCK20, SCK21,	
EVsso, EVss1:	Ground for port	SCLA0, SCLA1:	Serial clock input/output
EXCLK:	External clock input (Main	SCLA0, SCLA1, SCL00,	
	system clock)	SCL01, SCL10, SCL11,	
EXCLKS:	External clock input	SCL20,SCL21, SCL30,	
	(Subsystem clock)	SCL31:	Serial clock output
INTP0 to INTP11:	Interrupt request from	SDAA0, SDAA1, SDA00,	
	peripheral	SDA01,SDA10, SDA11,	
KR0 to KR7:	Key return	SDA20,SDA21, SDA30,	
P00 to P07:	Port 0	SDA31:	Serial data input/output
P10 to P17:	Port 1	SI00, SI01, SI10, SI11,	
P20 to P27:	Port 2	SI20, SI21, SI30, SI31:	Serial data input
P30 to P37:	Port 3	SO00, SO01, SO10,	
P40 to P47:	Port 4	SO11, SO20, SO21,	
P50 to P57:	Port 5	SO30, SO31:	Serial data output
P60 to P67:	Port 6	TI00 to TI07,	
P70 to P77:	Port 7	TI10 to TI17:	Timer input
P80 to P87:	Port 8	TO00 to TO07,	
P90 to P97:	Port 9	TO10 to TO17:	Timer output
P100 to P106:	Port 10	TOOL0:	Data input/output for tool
P110 to P117:	Port 11	TOOLRxD, TOOLTxD:	Data input/output for external device
P120 to P127:	Port 12	TxD0 to TxD3:	Transmit data
P130, P137:	Port 13	VDD:	Power supply
P140 to P147:	Port 14	Vss:	Ground
P150 to P156:	Port 15	X1, X2:	Crystal oscillator (main system clock)
PCLBUZ0, PCLBUZ1:	Programmable clock	XT1, XT2:	Crystal oscillator (subsystem clock)
	output/buzzer output		



(1) Flash ROM: 16 to 64 KB of 20- to 64-pin products

(TA = -40 to +85°C, 1.6 V \leq EVDD0 \leq VDD \leq 5.5 V, Vss = EVss0 = 0 V) (2/2)

Parameter	Symbol			Conditions		MIN.	TYP.	MAX.	Unit
Supply	IDD2	HALT	HS (high-	$f_{IH} = 32 \text{ MHz}^{Note 4}$	$V_{DD} = 5.0 V$		0.54	1.63	mA
Current	Note 2	mode	speed main) mode ^{Note 7}		$V_{DD} = 3.0 V$		0.54	1.63	mA
				fiH = 24 MHz ^{Note 4}	$V_{DD} = 5.0 V$		0.44	1.28	mA
			V _{DD} = 3.0 V		0.44	1.28	mA		
				fin = 16 MHz ^{Note 4}	V _{DD} = 5.0 V		0.40	1.00	mA
					V _{DD} = 3.0 V		0.40	1.00	mA
			LS (low-	fin = 8 MHz ^{Note 4}	V _{DD} = 3.0 V		260	530	μA
			speed main) mode ^{Note 7}		V _{DD} = 2.0 V		260	530	μA
			LV (low-	fiH = 4 MHz ^{Note 4}	V _{DD} = 3.0 V		420	640	μA
	voltage main) mode		V _{DD} = 2.0 V		420	640	μA		
	HS (hig speed	HS (high-	f _{MX} = 20 MHz ^{Note 3} ,	Square wave input		0.28	1.00	mA	
		speed main) mode ^{Note 7}	$V_{DD} = 5.0 V$	Resonator connection		0.45	1.17	mA	
				f _{MX} = 20 MHz ^{Note 3} ,	Square wave input		0.28	1.00	mA
				$V_{DD} = 3.0 V$	Resonator connection		0.45	1.17	mA
				$f_{MX} = 10 \text{ MHz}^{Note 3},$	Square wave input		0.19	0.60	mA
		$V_{DD} = 5.0 V$	Resonator connection		0.26	0.67	mA		
		$f_{MX} = 10 \text{ MHz}^{Note 3}$,	Square wave input		0.19	0.60	mA		
				$V_{DD} = 3.0 V$	Resonator connection		0.26	0.67	mA
			LS (low-	$f_{MX} = 8 MHz^{Note 3}$,	Square wave input		95	330	μA
			speed main)	$V_{DD} = 3.0 V$	Resonator connection		145	380	μA
			mode ^{Note 7}	$f_{MX} = 8 MHz^{Note 3}$,	Square wave input		95	330	μA
				$V_{DD} = 2.0 V$	Resonator connection		145	380	μA
			Subsystem	fsub = 32.768 kHz ^{Note 5}	Square wave input		0.25	0.57	μA
			clock	$T_A = -40^{\circ}C$	Resonator connection		0.44	0.76	μA
			operation	$f_{SUB} = 32.768 \text{ kHz}^{Note 5}$	Square wave input		0.30	0.57	μA
				$T_A = +25^{\circ}C$	Resonator connection		0.49	0.76	μA
				fsub = 32.768 kHz ^{Note 5}	Square wave input		0.37	1.17	μA
				$T_A = +50^{\circ}C$	Resonator connection		0.56	1.36	μA
				fsuв = 32.768 kHz ^{Note 5}	Square wave input		0.53	1.97	μA
				$T_A = +70^{\circ}C$	Resonator connection		0.72	2.16	μA
			fsub = 32.768 kHz ^{Note 5}	Square wave input		0.82	3.37	μA	
		T _A = +85°C	Resonator connection		1.01	3.56	μA		
	DD3 ^{Note 6}	STOP	$T_A = -40^{\circ}C$				0.18	0.50	μA
		mode ^{Note 8}	T _A = +25°C				0.23	0.50	μA
			$T_A = +50^{\circ}C$				0.30	1.10	μA
			$T_A = +70^{\circ}C$				0.46	1.90	μA
			T _A = +85°C				0.75	3.30	μA

(Notes and Remarks are listed on the next page.)



- **Notes 1.** Total current flowing into VDD, EVDDO, and EVDD1, including the input leakage current flowing when the level of the input pin is fixed to VDD, EVDDO, and EVDD1, or Vss, EVSSO, and EVSS1. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
 - 2. When high-speed on-chip oscillator and subsystem clock are stopped.
 - 3. When high-speed system clock and subsystem clock are stopped.
 - 4. When high-speed on-chip oscillator and high-speed system clock are stopped. When AMPHS1 = 1 (Ultra-low power consumption oscillation). However, not including the current flowing into the RTC, 12-bit interval timer, and watchdog timer.
 - **5.** Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.
 - HS (high-speed main) mode: $2.7 \text{ V} \le \text{V}_{\text{DD}} \le 5.5 \text{ V} @ 1 \text{ MHz}$ to 32 MHz
 - 2.4 V \leq V_{DD} \leq 5.5 V@1 MHz to 16 MHz
 - LS (low-speed main) mode: $~~1.8~V \leq V_{\text{DD}} \leq 5.5~V~$ @1 MHz to 8 MHz
 - LV (low-voltage main) mode: 1.6 V \leq V_DD \leq 5.5 V@1 MHz to 4 MHz
- Remarks 1. fmx: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
 - 2. fin: High-speed on-chip oscillator clock frequency
 - **3.** fsub: Subsystem clock frequency (XT1 clock oscillation frequency)
 - 4. Except subsystem clock operation, temperature condition of the TYP. value is $T_A = 25^{\circ}C$



Remarks 1. p: CSI number (p = 00, 01, 10, 11, 20, 21, 30, 31), m: Unit number (m = 0, 1), n: Channel number (n = 0 to 3),

g: PIM and POM numbers (g = 0, 1, 4, 5, 8, 14)

2. fmck: Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13))

(4) During communication at same potential (CSI mode) (slave mode, SCKp... external clock input) (1/2) ($T_A = -40$ to $+85^{\circ}$ C, 1.6 V \leq EV_{DD0} = EV_{DD1} \leq V_{DD} \leq 5.5 V, Vss = EV_{SS0} = EV_{SS1} = 0 V)

Parameter	Symbol	l Conditions			h-speed Mode		/-speed Mode	LV (low-voltage main) Mode		Unit
					MAX.	MIN.	MAX.	MIN.	MAX.	
SCKp cycle time	tkCY2	$4.0~V \leq EV_{DD0} \leq 5.5$	20 MHz < fмск	8/fмск		_		_		ns
Note 5		V	fмск \leq 20 MHz	6/fмск		6/fмск		6/fмск		ns
		$2.7~V \leq EV_{\text{DD0}} \leq 5.5$	16 MHz < fмск	8/fмск		_		_		ns
		V	fмск \leq 16 MHz	6/fмск		6/fмск		6/fмск		ns
		$2.4~V \leq EV_{\text{DD0}} \leq 5.5~V$		6/fмск and 500		6/fмск and 500		6/fмск and 500		ns
		$1.8~V \le EV_{DD0} \le 5.5~V$		6/fмск and 750		6/fмск and 750		6/fмск and 750		ns
		$1.7~V \leq EV_{DD0} \leq 5.5~V$		6/fмск and 1500		6/fмск and 1500		6/fмск and 1500		ns
		$1.6 \ V \leq EV_{\text{DD0}} \leq 5.5$	V	—		6/fмск and 1500		6/fмск and 1500		ns
SCKp high-/low- level width	tкн2, tкL2	$4.0~V \le EV_{DD0} \le 5.5~V$		tксү2/2 – 7		tксү2/2 - 7		tксү2/2 - 7		ns
		$2.7~V \leq EV_{DD0} \leq 5.5~V$		tксү2/2 – 8		tксү2/2 - 8		tксү2/2 - 8		ns
		$1.8~V \le EV_{DD0} \le 5.5~V$		tксү2/2 – 18		tксү2/2 – 18		tксү2/2 – 18		ns
		$1.7~V \leq EV_{DD0} \leq 5.5~V$		tксү2/2 – 66		tксү2/2 - 66		tксү2/2 - 66		ns
		$1.6~V \le EV_{\text{DD0}} \le 5.5$	V	_		tксү2/2 - 66		tксү2/2 - 66		ns

(Notes, Caution, and Remarks are listed on the next page.)



Parameter	Symbol	Conditions	、 U	h-speed Mode	``	/-speed Mode	`	-voltage Mode	Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
Data setup time (reception)	tsu:dat	$\label{eq:states} \begin{array}{l} 2.7 \ V \leq EV_{\text{DD0}} \leq 5.5 \ V, \\ C_{\text{b}} = 50 \ pF, \ R_{\text{b}} = 2.7 \ k\Omega \end{array}$	1/fмск + 85 _{Note2}		1/fмск + 145 _{Note2}		1/fмск + 145 _{Note2}		ns
		$\label{eq:linear} \begin{split} 1.8 \ V &\leq EV_{\text{DD0}} \leq 5.5 \ V, \\ C_{\text{b}} &= 100 \ \text{pF}, \ R_{\text{b}} = 3 \ \text{k}\Omega \end{split}$	1/fмск + 145 _{Note2}		1/fмск + 145 _{Note2}		1/fмск + 145 _{Note2}		ns
		$\label{eq:linear} \begin{split} 1.8 \ V &\leq EV_{\text{DD0}} < 2.7 \ V, \\ C_{\text{b}} &= 100 \ \text{pF}, \ R_{\text{b}} = 5 \ \text{k}\Omega \end{split}$	1/fмск + 230 _{Note2}		1/f _{MCK} + 230 _{Note2}		1/fмск + 230 _{Note2}		ns
		$\label{eq:linear} \begin{array}{l} 1.7 \mbox{ V} \leq EV_{\mbox{DD0}} < 1.8 \mbox{ V}, \\ C_{\mbox{b}} = 100 \mbox{ pF}, \mbox{ R}_{\mbox{b}} = 5 \mbox{ k}\Omega \end{array}$	1/fмск + 290 _{Note2}		1/f _{MCK} + 290 _{Note2}		1/fмск + 290 _{Note2}		ns
		$\label{eq:linear} \begin{array}{l} 1.6 \mbox{ V} \leq EV_{\mbox{DD0}} < 1.8 \mbox{ V}, \\ C_{\mbox{\tiny b}} = 100 \mbox{ pF}, \mbox{ R}_{\mbox{\tiny b}} = 5 k\Omega \end{array}$	—		1/f _{MCK} + 290 _{Note2}		1/fмск + 290 _{Note2}		ns
Data hold time (transmission)	thd:dat	$\begin{array}{l} 2.7 \ \text{V} \leq \text{EV}_{\text{DD0}} \leq 5.5 \ \text{V}, \\ \text{C}_{\text{b}} = 50 \ \text{pF}, \ \text{R}_{\text{b}} = 2.7 \ \text{k}\Omega \end{array}$	0	305	0	305	0	305	ns
		$\label{eq:linear} \begin{array}{l} 1.8 \mbox{ V} \leq EV_{\mbox{DD0}} \leq 5.5 \mbox{ V}, \\ C_{\mbox{\tiny b}} = 100 \mbox{ pF}, \mbox{ R}_{\mbox{\tiny b}} = 3 k\Omega \end{array}$	0	355	0	355	0	355	ns
		$\label{eq:linear} \begin{array}{l} 1.8 \mbox{ V} \leq EV_{\mbox{DD0}} < 2.7 \mbox{ V}, \\ C_{\mbox{\tiny b}} = 100 \mbox{ pF}, \mbox{ R}_{\mbox{\tiny b}} = 5 k\Omega \end{array}$	0	405	0	405	0	405	ns
		$1.7 \text{ V} \leq \text{EV}_{\text{DD0}} < 1.8 \text{ V},$ $C_{\text{b}} = 100 \text{ pF}, \text{ R}_{\text{b}} = 5 \text{ k}\Omega$	0	405	0	405	0	405	ns
		$1.6 \text{ V} \leq \text{EV}_{\text{DD0}} < 1.8 \text{ V},$ $C_{\text{b}} = 100 \text{ pF}, \text{ R}_{\text{b}} = 5 \text{ k}\Omega$	_	_	0	405	0	405	ns

(5)	During communication at same potential (simplified I ² C mode) (2/2)
	$(T_{A} = -40 \text{ to } +85^{\circ}\text{C}, 1.6 \text{ V} \le \text{EV}_{\text{DD0}} = \text{EV}_{\text{DD1}} \le \text{V}_{\text{DD}} \le 5.5 \text{ V}, \text{Vss} = \text{EV}_{\text{SS0}} = \text{EV}_{\text{SS1}} = 0 \text{ V})$

Notes 1. The value must also be equal to or less than $f_{MCK}/4$.

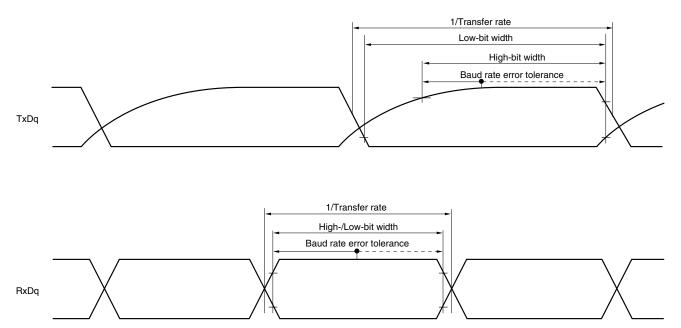
2. Set the fMCK value to keep the hold time of SCLr = "L" and SCLr = "H".

Caution Select the normal input buffer and the N-ch open drain output (VDD tolerance (When 20- to 52-pin products)/EVDD tolerance (When 64- to 128-pin products)) mode for the SDAr pin and the normal output mode for the SCLr pin by using port input mode register g (PIMg) and port output mode register h (POMh).

(**Remarks** are listed on the next page.)







- **2.** q: UART number (q = 0 to 3), g: PIM and POM number (g = 0, 1, 8, 14)
- **3.** fMCK: Serial array unit operation clock frequency
 (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn).
 m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13))
- **4.** UART2 cannot communicate at different potential when bit 1 (PIOR1) of peripheral I/O redirection register (PIOR) is 1.



(2) When reference voltage (+) = AV_{REFP}/ANI0 (ADREFP1 = 0, ADREFP0 = 1), reference voltage (-) = AV_{REFM}/ANI1 (ADREFM = 1), target pin : ANI16 to ANI26

$(T_{A} = -40 \text{ to } +85^{\circ}\text{C}, 1.6 \text{ V} \le \text{EV}_{\text{DD0}} = \text{EV}_{\text{DD1}} \le \text{V}_{\text{DD}} \le 5.5 \text{ V}, 1.6 \text{ V} \le \text{AV}_{\text{REFP}} \le \text{V}_{\text{DD}} \le 5.5 \text{ V}, \text{V}_{\text{SS}} = \text{EV}_{\text{SS0}} = \text{EV}_{\text{SS1}} = 0 \text{ V},$
Reference voltage (+) = AVREFP, Reference voltage (–) = AVREFM = 0 V)

Parameter	Symbol	Condit	ions	MIN.	TYP.	MAX.	Unit
Resolution	RES			8		10	bit
Overall error ^{Note 1}	AINL	10-bit resolution	$1.8~V \leq AV_{\text{REFP}} \leq 5.5~V$		1.2	±5.0	LSB
		$EVDD0 = AV_{REFP} = V_{DD}^{Notes 3, 4}$	$1.6~V \leq AV_{REFP} \leq 5.5~V^{Note}$		1.2	±8.5	LSB
Conversion time	t CONV	10-bit resolution	$3.6~V \le V \text{DD} \le 5.5~V$	2.125		39	μs
		Target ANI pin : ANI16 to	$2.7~V \leq V \text{DD} \leq 5.5~V$	3.1875		39	μS
		ANI26	$1.8~V \leq V \text{DD} \leq 5.5~V$	17		39	μs
			$1.6~V \leq V \text{DD} \leq 5.5~V$	57		95	μs
Zero-scale error ^{Notes 1, 2}	Ezs	10-bit resolution	$1.8~V \leq AV_{\text{REFP}} \leq 5.5~V$			±0.35	%FSR
		$EVDD0 = AV_{REFP} = V_{DD}^{Notes 3, 4}$	$1.6~V \leq AV_{\text{REFP}} \leq 5.5~V^{\text{Note}}$			±0.60	%FSR
Full-scale error ^{Notes 1, 2}	Efs	10-bit resolution	$1.8~V \leq AV_{\text{REFP}} \leq 5.5~V$			±0.35	%FSR
		$EVDD0 = AV_{REFP} = V_{DD}^{Notes 3, 4}$	$1.6~V \leq AV_{REFP} \leq 5.5~V^{Note}$			±0.60	%FSR
Integral linearity error ^{Note}	ILE	10-bit resolution	$1.8~V \leq AV_{\text{REFP}} \leq 5.5~V$			±3.5	LSB
1		$EVDD0 = AV_{REFP} = V_{DD}^{Notes 3, 4}$	$1.6~V \leq AV_{REFP} \leq 5.5~V^{Note}$			±6.0	LSB
Differential linearity	DLE	10-bit resolution	$1.8~V \leq AV_{\text{REFP}} \leq 5.5~V$			±2.0	LSB
error ^{Note 1}		$EVDD0 = AV_{REFP} = V_{DD}^{Notes 3, 4}$	$1.6~V \leq AV_{REFP} \leq 5.5~V^{Note}$			±2.5	LSB
Analog input voltage	VAIN	ANI16 to ANI26	·	0		AVREFP and EVDD0	V

Notes 1. Excludes quantization error ($\pm 1/2$ LSB).

- 2. This value is indicated as a ratio (%FSR) to the full-scale value.
- 3. When AV_{REFP} < V_{DD}, the MAX. values are as follows. Overall error: Add ± 1.0 LSB to the MAX. value when AV_{REFP} = V_{DD}. Zero-scale error/Full-scale error: Add $\pm 0.05\%$ FSR to the MAX. value when AV_{REFP} = V_{DD}. Integral linearity error/ Differential linearity error: Add ± 0.5 LSB to the MAX. value when AV_{REFP} = V_{DD}.
- 4. When AV_{REFP} < EV_{DD0} ≤ V_{DD}, the MAX. values are as follows. Overall error: Add ±4.0 LSB to the MAX. value when AV_{REFP} = V_{DD}. Zero-scale error/Full-scale error: Add ±0.20%FSR to the MAX. value when AV_{REFP} = V_{DD}. Integral linearity error/ Differential linearity error: Add ±2.0 LSB to the MAX. value when AV_{REFP} = V_{DD}.
- 5. When the conversion time is set to 57 μ s (min.) and 95 μ s (max.).



3.3.2 Supply current characteristics

Parameter	Symbol			Conditions			MIN.	TYP.	MAX.	Unit	
Supply	IDD1	Operating	HS (high-	$f_{IH}=32~MHz^{Note~3}$	Basic	$V_{DD} = 5.0 V$		2.1		mA	
Current Note 1		mode	speed main) mode ^{Note 5}		operatio n	Vdd = 3.0 V		2.1		mA	
					Normal	$V_{DD} = 5.0 V$		4.6	7.5	mA	
					operatio n	$V_{DD} = 3.0 V$		4.6	7.5	mA	
				$f_{IH} = 24 \text{ MHz}^{Note 3}$	Normal	$V_{DD} = 5.0 V$		3.7	5.8	mA	
					operatio n	$V_{DD} = 3.0 V$		3.7	5.8	mA	
				$f_{IH} = 16 \text{ MHz}^{Note 3}$	Normal	$V_{DD} = 5.0 V$		2.7	4.2	mA	
					operatio n	V _{DD} = 3.0 V		2.7	4.2	mA	
			HS (high-	$f_{MX} = 20 \text{ MHz}^{Note 2},$	Normal	Square wave input		3.0	4.9	mA	
		speed	speed main) mode ^{№ote 5}	$V_{DD} = 5.0 V$	operatio n	Resonator connection		3.2	5.0	mA	
				$f_{MX} = 20 \text{ MHz}^{Note 2},$	Normal	Square wave input		3.0	4.9	mA	
					$V_{DD} = 3.0 V$	operatio n	Resonator connection		3.2	5.0	mA
				$f_{MX} = 10 \text{ MHz}^{Note 2},$	Normal	Square wave input		1.9	2.9	mA	
		Subsystem fs clock		V _{DD} = 5.0 V	$V_{DD} = 5.0 V$	operatio n	Resonator connection		1.9	2.9	mA
			$f_{MX} = 10 \text{ MHz}^{Note 2},$	Normal	Square wave input		1.9	2.9	mA		
					$V_{DD} = 3.0 V$	operatio n	Resonator connection		1.9	2.9	mA
			Subsystem	fsuв = 32.768 kHz	Normal	Square wave input		4.1	4.9	μA	
						Note 4 $T_A = -40^{\circ}C$	operatio n	Resonator connection		4.2	5.0
				fsuв = 32.768 kHz	Normal	Square wave input		4.1	4.9	μA	
					Note 4 $T_A = +25^{\circ}C$	operatio n	Resonator connection		4.2	5.0	μA
				fsuв = 32.768 kHz	Normal	Square wave input		4.2	5.5	μA	
				Note 4 $T_A = +50^{\circ}C$	operatio n	Resonator connection		4.3	5.6	μA	
				fsuв = 32.768 kHz	Normal	Square wave input		4.3	6.3	μA	
				Note 4	operatio n	Resonator connection		4.4	6.4	μA	
				$T_A = +70^{\circ}C$	Newsel			4.0	~ ~		
				fsub = 32.768 kHz Note 4	Normal operation	Square wave input		4.6	7.7	μA	
				T _A = +85°C	sportuoli	Resonator connection		4.7	7.8	μA	
				fsuв = 32.768 kHz	Normal	Square wave input		6.9	19.7	μA	
				_{Note 4} T _A = +105°C	operation	Resonator connection		7.0	19.8	μA	

(1) Flash ROM: 16 to 64 KB of 20- to 64-pin products (TA = -40 to $+105^{\circ}$ C, 2.4 V $\leq EV_{DD0} \leq V_{DD} \leq 5.5$ V, Vss = EVss₀ = 0 V) (1/2)

(Notes and Remarks are listed on the next page.)



- **Notes 1.** Total current flowing into V_{DD} and EV_{DD0}, including the input leakage current flowing when the level of the input pin is fixed to V_{DD}, EV_{DD0} or Vss, EV_{SS0}. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
 - 2. When high-speed on-chip oscillator and subsystem clock are stopped.
 - 3. When high-speed system clock and subsystem clock are stopped.
 - 4. When high-speed on-chip oscillator and high-speed system clock are stopped. When AMPHS1 = 1 (Ultra-low power consumption oscillation). However, not including the current flowing into the RTC, 12-bit interval timer, and watchdog timer.
 - 5. Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.

HS (high-speed main) mode: 2.7 V \leq V_DD \leq 5.5 V@1 MHz to 32 MHz

2.4 V
$$\leq$$
 V_{DD} \leq 5.5 V@1 MHz to 16 MHz

- **Remarks 1.** f_{MX}: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
 - 2. fin: High-speed on-chip oscillator clock frequency
 - 3. fsub: Subsystem clock frequency (XT1 clock oscillation frequency)
 - 4. Except subsystem clock operation, temperature condition of the TYP. value is $T_A = 25^{\circ}C$



Parameter	Symbol	Conditions	HS (high-spee	ed main) Mode	Unit
		T	MIN.	MAX.	
SIp setup time	tsik1	$4.0 \ V \leq EV_{\text{DD}} \leq 5.5 \ V, \ 2.7 \ V \leq V_{\text{b}} \leq 4.0 \ V,$	88		ns
(to SCKp↓) ^{Note}		$C_b = 30 \text{ pF}, \text{ R}_b = 1.4 \text{ k}\Omega$			
		$2.7 \ V \leq EV_{\text{DD0}} < 4.0 \ V, \ 2.3 \ V \leq V_b \leq 2.7 \ V,$	88		ns
		C_b = 30 pF, R_b = 2.7 k Ω			
		$2.4 \ V \leq EV_{\text{DD0}} < 3.3 \ V, \ 1.6 \ V \leq V_b \leq 2.0 \ V,$	220		ns
		C_b = 30 pF, R_b = 5.5 k Ω			
Slp hold time (from SCKp↓) ^{№te}	tksi1	$4.0~V \leq EV_{\text{DD0}} \leq 5.5~V,~2.7~V \leq V_b \leq 4.0~V,$	38		ns
		$C_b = 30 \text{ pF}, \text{R}_b = 1.4 \text{k}\Omega$			
		$2.7 \ V \leq EV_{\text{DD0}} < 4.0 \ V, \ 2.3 \ V \leq V_b \leq 2.7 \ V,$	38		ns
		$C_b=30 \text{ pF}, \text{R}_b=2.7 \text{k}\Omega$			
		$2.4~V \leq EV_{\text{DD0}} < 3.3~V,~1.6~V \leq V_{\text{b}} \leq 2.0~V,$	38		ns
		$C_b=30 \text{ pF}, \text{R}_b=5.5 \text{k}\Omega$			
Delay time from SCKp↑ to	tkso1	$4.0~V \leq EV_{\text{DD0}} \leq 5.5~V,~2.7~V \leq V_{\text{b}} \leq 4.0~V,$		50	ns
SOp output Note		C_b = 30 pF, R_b = 1.4 k Ω			
		$2.7 \ V \leq EV_{\text{DD0}} < 4.0 \ V, \ 2.3 \ V \leq V_b \leq 2.7 \ V,$		50	ns
		$C_b=30 \text{ pF}, \text{R}_b=2.7 \text{k}\Omega$			
		$2.4 \ V \leq EV_{\text{DD0}} < 3.3 \ V, \ 1.6 \ V \leq V_b \leq 2.0 \ V,$		50	ns
		$C_b = 30 \text{ pF}, R_b = 5.5 \text{ k}\Omega$			

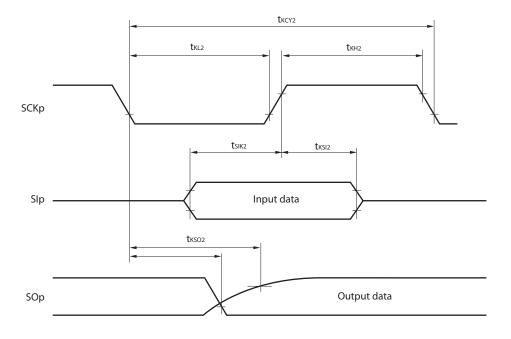
(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output) (3/3)

Note When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

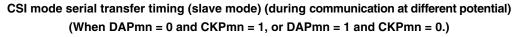
Caution Select the TTL input buffer for the SIp pin and the N-ch open drain output (V_{DD} tolerance (for the 20- to 52-pin products)/EV_{DD} tolerance (for the 64- to 100-pin products)) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL}, see the DC characteristics with TTL input buffer selected.

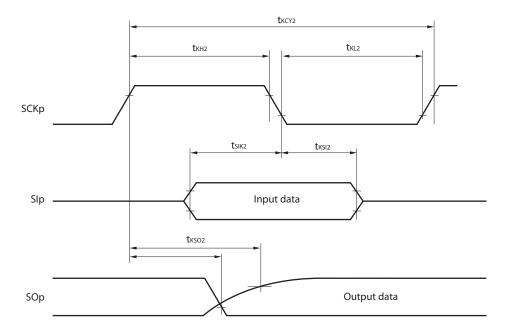
(**Remarks** are listed on the next page.)





CSI mode serial transfer timing (slave mode) (during communication at different potential) (When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)





Remarks 1. p: CSI number (p = 00, 01, 10, 20, 30, 31), m: Unit number,

n: Channel number (mn = 00, 01, 02, 10, 12. 13), g: PIM and POM number (g = 0, 1, 4, 5, 8, 14)

2. CSI01 of 48-, 52-, 64-pin products, and CSI11 and CSI21 cannot communicate at different potential. Use other CSI for communication at different potential.



(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I²C mode) (1/2) (T_A = -40 to +105°C, 2.4 V \leq EVpp0 = EVpp1 \leq Vpp \leq 5.5 V, Vss = EVss0 = EVss1 = 0 V)

Parameter	Symbol	Conditions		peed main) ode	Unit
			MIN.	MAX.	
SCLr clock frequency	fscL	$\begin{split} 4.0 \ V &\leq EV_{DD0} \leq 5.5 \ V, \\ 2.7 \ V &\leq V_b \leq 4.0 \ V, \\ C_b &= 50 \ pF, \ R_b = 2.7 \ k\Omega \end{split}$		400 ^{Note 1}	kHz
		$\label{eq:VDD} \begin{split} & 2.7 \; V \leq EV_{DD0} < 4.0 \; V, \\ & 2.3 \; V \leq V_b \leq 2.7 \; V, \\ & C_b = 50 \; pF, \; R_b = 2.7 \; k\Omega \end{split}$		400 ^{Note 1}	kHz
				100 ^{Note 1}	kHz
		$\label{eq:2.7} \begin{split} & 2.7 \; V \leq EV_{DD0} < 4.0 \; V, \\ & 2.3 \; V \leq V_b \leq 2.7 \; V, \\ & C_b = 100 \; pF, \; R_b = 2.7 \; k\Omega \end{split}$		100 ^{Note 1}	kHz
		$\label{eq:2.4} \begin{split} 2.4 \ V &\leq EV_{\text{DD0}} < 3.3 \ V, \\ 1.6 \ V &\leq V_b \leq 2.0 \ V, \\ C_b &= 100 \ pF, \ R_b = 5.5 \ k\Omega \end{split}$		100 ^{Note 1}	kHz
Hold time when SCLr = "L"	t∟ow	$ \begin{split} & 4.0 \; V \leq EV_{DD0} \leq 5.5 \; V, \\ & 2.7 \; V \leq V_b \leq 4.0 \; V, \\ & C_b = 50 \; pF, \; R_b = 2.7 \; k\Omega \end{split} $	1200		ns
		$\label{eq:2.7} \begin{split} & 2.7 \; V \leq EV_{DD0} < 4.0 \; V, \\ & 2.3 \; V \leq V_b \leq 2.7 \; V, \\ & C_b = 50 \; pF, \; R_b = 2.7 \; k\Omega \end{split}$	1200		ns
		$\label{eq:loss} \begin{split} & 4.0 \ V \leq EV_{DD0} \leq 5.5 \ V, \\ & 2.7 \ V \leq V_b \leq 4.0 \ V, \\ & C_b = 100 \ pF, \ R_b = 2.8 \ k\Omega \end{split}$	4600		ns
		$\label{eq:VDD} \begin{split} & 2.7 \; V \leq EV_{DD0} < 4.0 \; V, \\ & 2.3 \; V \leq V_b \leq 2.7 \; V, \\ & C_b = 100 \; pF, \; R_b = 2.7 \; k\Omega \end{split}$	4600		ns
		$\label{eq:2.4} \begin{split} & 2.4 \; V \leq EV_{DD0} < 3.3 \; V, \\ & 1.6 \; V \leq V_b \leq 2.0 \; V, \\ & C_b = 100 \; pF, \; R_b = 5.5 \; k\Omega \end{split}$	4650		ns
Hold time when SCLr = "H"	tніgн		620		ns
		$\label{eq:2.7} \begin{split} & 2.7 \; V \leq EV_{DD0} < 4.0 \; V, \\ & 2.3 \; V \leq V_{b} \leq 2.7 \; V, \\ & C_{b} = 50 \; pF, \; R_{b} = 2.7 \; k\Omega \end{split}$	500		ns
		$\begin{array}{l} 4.0 \; V \leq EV_{DD0} \leq 5.5 \; V, \\ 2.7 \; V \leq V_b \leq 4.0 \; V, \\ C_b = 100 \; pF, \; R_b = 2.8 \; k\Omega \end{array}$	2700		ns
		$\label{eq:2.7} \begin{split} & 2.7 \ V \leq EV_{\text{DD0}} < 4.0 \ V, \\ & 2.3 \ V \leq V_b \leq 2.7 \ V, \\ & C_b = 100 \ pF, \ R_b = 2.7 \ k\Omega \end{split}$	2400		ns
		$\label{eq:2.4} \begin{split} & 2.4 \; V \leq EV_{\text{DD0}} < 3.3 \; V, \\ & 1.6 \; V \leq V_b \leq 2.0 \; V, \\ & C_b = 100 \; pF, \; R_b = 5.5 \; k\Omega \end{split}$	1830		ns

(Notes and Caution are listed on the next page, and Remarks are listed on the page after the next page.)



Parameter	Symbol	Conditions	HS (high-sp Mo		Unit
			MIN.	MAX.	
Data setup time (reception)	tsu:dat		1/fмск + 340 Note 2		ns
		$\label{eq:2.7} \begin{split} & 2.7 \; V \leq EV_{DD0} < 4.0 \; V, \\ & 2.3 \; V \leq V_b \leq 2.7 \; V, \\ & C_b = 50 \; pF, \; R_b = 2.7 \; k\Omega \end{split}$	1/fмск + 340 Note 2		ns
			1/fмск + 760 Note 2		ns
		$\label{eq:2.7} \begin{split} & 2.7 \; V \leq EV_{DD0} < 4.0 \; V, \\ & 2.3 \; V \leq V_b \leq 2.7 \; V, \\ & C_b = 100 \; pF, \; R_b = 2.7 \; k\Omega \end{split}$	1/fмск + 760 Note 2		ns
		$\label{eq:2.4} \begin{split} & 2.4 \; V \leq EV_{DD0} < 3.3 \; V, \\ & 1.6 \; V \leq V_b \leq 2.0 \; V, \\ & C_b = 100 \; pF, \; R_b = 5.5 \; k\Omega \end{split}$	1/fмск + 570 Note 2		ns
Data hold time (transmission)	thd:dat		0	770	ns
		$\label{eq:2.7} \begin{split} & 2.7 \; V \leq EV_{DD0} < 4.0 \; V, \\ & 2.3 \; V \leq V_b \leq 2.7 \; V, \\ & C_b = 50 \; pF, \; R_b = 2.7 \; k\Omega \end{split}$	0	770	ns
			0	1420	ns
		$\label{eq:2.7} \begin{array}{l} 2.7 \; V \leq EV_{DD0} < 4.0 \; V, \\ 2.3 \; V \leq V_b \leq 2.7 \; V, \\ C_b = 100 \; pF, \; R_b = 2.7 \; k\Omega \end{array}$	0	1420	ns
		$\label{eq:2.4} \begin{array}{l} 2.4 \; V \leq EV_{DD0} < 3.3 \; V, \\ 1.6 \; V \leq V_b \leq 2.0 \; V, \\ C_b = 100 \; pF, \; R_b = 5.5 \; k\Omega \end{array}$	0	1215	ns

(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I²C mode) (2/2) (T_A = -40 to +105°C, 2.4 V \leq EV_{DD0} = EV_{DD1} \leq V_{DD} \leq 5.5 V, Vss = EV_{SS0} = EV_{SS1} = 0 V)

Notes 1. The value must also be equal to or less than $f_{MCK}/4$.

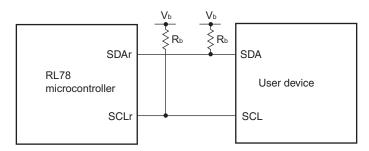
2. Set the fMCK value to keep the hold time of SCLr = "L" and SCLr = "H".

Caution Select the TTL input buffer and the N-ch open drain output (V_{DD} tolerance (for the 20- to 52-pin products)/EV_{DD} tolerance (for the 64- to 100-pin products)) mode for the SDAr pin and the N-ch open drain output (V_{DD} tolerance (for the 20- to 52-pin products)/EV_{DD} tolerance (for the 64- to 100-pin products)) mode for the SCLr pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL}, see the DC characteristics with TTL input buffer selected.

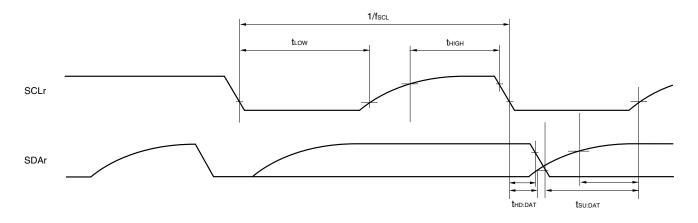
(**Remarks** are listed on the next page.)



Simplified I²C mode connection diagram (during communication at different potential)



Simplified I²C mode serial transfer timing (during communication at different potential)



- Caution Select the TTL input buffer and the N-ch open drain output (V_{DD} tolerance (for the 20- to 52-pin products)/EV_{DD} tolerance (for the 64- to 100-pin products)) mode for the SDAr pin and the N-ch open drain output (V_{DD} tolerance (for the 20- to 52-pin products)/EV_{DD} tolerance (for the 64- to 100-pin products)) mode for the SCLr pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL}, see the DC characteristics with TTL input buffer selected.
- **Remarks 1.** R_b[Ω]:Communication line (SDAr, SCLr) pull-up resistance, C_b[F]: Communication line (SDAr, SCLr) load capacitance, V_b[V]: Communication line voltage
 - 2. r: IIC number (r = 00, 01, 10, 20, 30, 31), g: PIM, POM number (g = 0, 1, 4, 5, 8, 14)
 - 3. fMCK: Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number,

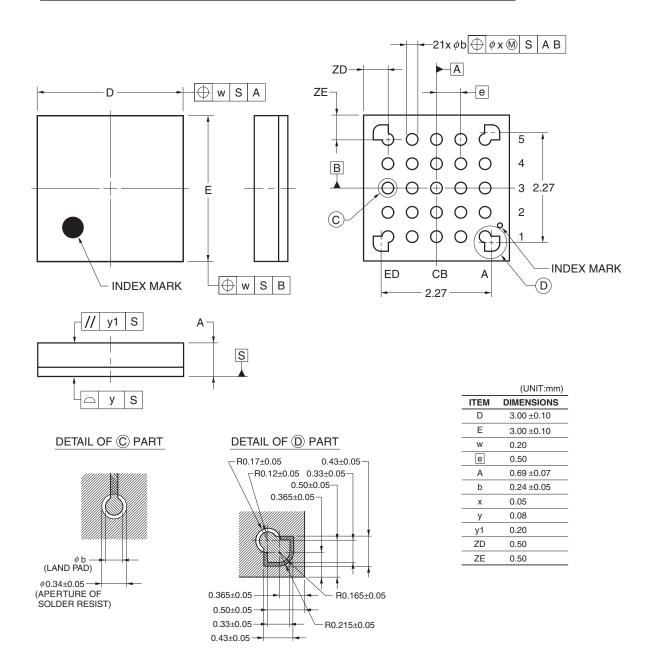
n: Channel number (mn = 00, 01, 02, 10, 12, 13)



4.3 25-pin Products

R5F1008AALA, R5F1008CALA, R5F1008DALA, R5F1008EALA R5F1018AALA, R5F1018CALA, R5F1018DALA, R5F1018EALA R5F1008AGLA, R5F1008CGLA, R5F1008DGLA, R5F1008EGLA

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-WFLGA25-3x3-0.50	PWLG0025KA-A	P25FC-50-2N2-2	0.01

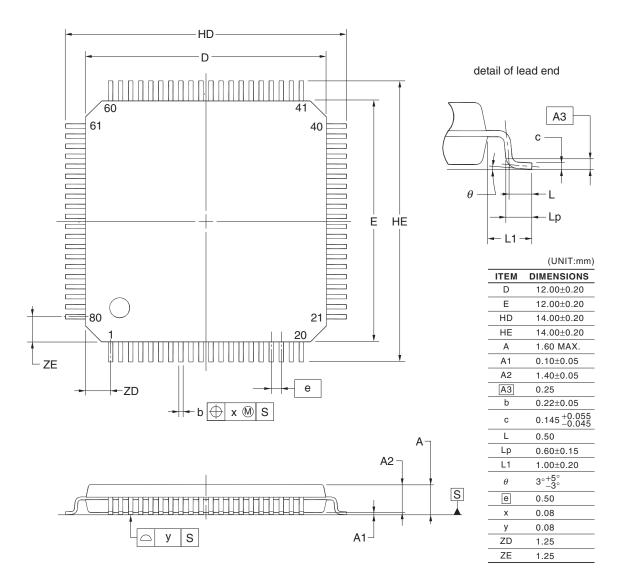


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R5F100MFAFB, R5F100MGAFB, R5F100MHAFB, R5F100MJAFB, R5F100MKAFB, R5F100MLAFB R5F101MFAFB, R5F101MGAFB, R5F101MHAFB, R5F101MJAFB, R5F101MKAFB, R5F101MLAFB R5F100MFDFB, R5F100MGDFB, R5F100MHDFB, R5F100MJDFB, R5F100MKDFB, R5F100MLDFB R5F101MFDFB, R5F101MGDFB, R5F101MHDFB, R5F101MJDFB, R5F101MKDFB, R5F101MLDFB R5F100MFGFB, R5F100MGGFB, R5F100MHGFB, R5F100MJGFB

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-LFQFP80-12x12-0.50	PLQP0080KE-A	P80GK-50-8EU-2	0.53



NOTE

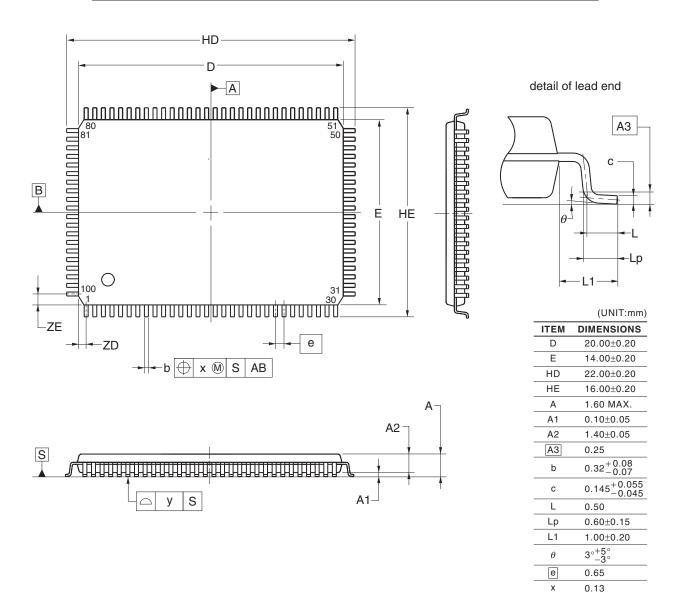
Each lead centerline is located within 0.08 mm of its true position at maximum material condition.

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R5F100PFAFA, R5F100PGAFA, R5F100PHAFA, R5F100PJAFA, R5F100PKAFA, R5F100PLAFA R5F101PFAFA, R5F101PGAFA, R5F101PHAFA, R5F101PJAFA, R5F101PKAFA, R5F101PLAFA R5F100PFDFA, R5F100PGDFA, R5F100PHDFA, R5F100PJDFA, R5F100PKDFA, R5F100PLDFA R5F101PFDFA, R5F101PGDFA, R5F101PHDFA, R5F101PJDFA, R5F101PKDFA, R5F101PLDFA R5F100PFGFA, R5F100PGGFA, R5F100PHGFA, R5F100PJGFA

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-LQFP100-14x20-0.65	PLQP0100JC-A	P100GF-65-GBN-1	0.92



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0.10

0.575

0.825

y ZD

ZE

			Description		
Rev.	Date	Page	Summary		
3.00	Aug 02, 2013	118	Modification of table in 2.6.2 Temperature sensor/internal reference voltage characteristics		
		118	Modification of table and note in 2.6.3 POR circuit characteristics		
		119	Modification of table in 2.6.4 LVD circuit characteristics		
		120	Modification of table of LVD Detection Voltage of Interrupt & Reset Mode		
		120	Renamed to 2.6.5 Power supply voltage rising slope characteristics		
		122	Modification of table, figure, and remark in 2.10 Timing Specs for Switching Flash Memory Programming Modes		
		123	Modification of caution 1 and description		
		124	Modification of table and remark 3 in Absolute Maximum Ratings ($T_A = 25^{\circ}C$)		
		126	Modification of table, note, caution, and remark in 3.2.1 X1, XT1 oscillator characteristics		
		126	Modification of table in 3.2.2 On-chip oscillator characteristics		
		127	Modification of note 3 in 3.3.1 Pin characteristics (1/5)		
		128	Modification of note 3 in 3.3.1 Pin characteristics (2/5)		
		133	Modification of notes 1 and 4 in (1) Flash ROM: 16 to 64 KB of 20- to 64-pin products (1/2)		
		135	Modification of notes 1, 5, and 6 in (1) Flash ROM: 16 to 64 KB of 20- to 64- pin products (2/2)		
		137	Modification of notes 1 and 4 in (2) Flash ROM: 96 to 256 KB of 30- to 100- pin products (1/2)		
		139	Modification of notes 1, 5, and 6 in (2) Flash ROM: 96 to 256 KB of 30- to 100-pin products (2/2)		
		140	Modification of (3) Peripheral Functions (Common to all products)		
		142	Modification of table in 3.4 AC Characteristics		
		143	Addition of Minimum Instruction Execution Time during Main System Clock Operation		
		143	Modification of figure of AC Timing Test Points		
		143	Modification of figure of External System Clock Timing		
		145	Modification of figure of AC Timing Test Points		
		145	Modification of description, note 1, and caution in (1) During communication at same potential (UART mode)		
		146	Modification of description in (2) During communication at same potential (CSI mode)		
		147	Modification of description in (3) During communication at same potential (CSI mode)		
		149	Modification of table, note 1, and caution in (4) During communication at same potential (simplified I ² C mode)		
		151	Modification of table, note 1, and caution in (5) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode) (1/2)		
		152 to 154	Modification of table, notes 2 to 6, caution, and remarks 1 to 4 in (5) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode) (2/2)		
		155	Modification of table in (6) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (1/3)		
		156	Modification of table and caution in (6) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (2/3)		
		157, 158	Modification of table, caution, and remarks 3 and 4 in (6) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (3/3)		
		160, 161	Modification of table and caution in (7) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode)		